High-strength AlN ceramics by low-temperature sintering with CaZrO$_3$–Y$_2$O$_3$ co-additives

Hyun Min Lee, Do Kyung Kim

Department of Materials Science and Engineering, Korea Advanced Institute of Science and Technology (KAIST), 291 Daehak-ro, Yuseong-gu, Daejeon 305-701, Republic of Korea

Received 5 March 2014; received in revised form 3 May 2014; accepted 5 May 2014
Available online 2 June 2014

Abstract

Aluminum nitride (AlN) ceramics with the concurrent addition of CaZrO$_3$ and Y$_2$O$_3$ were sintered at 1450-1700 °C. The degree of densification, microstructure, flexural strength, and thermal conductivity of the resulting ceramics were evaluated with respect to their composition and sintering temperature. Specimens prepared using both additives could be sintered to almost full density at relatively low temperature (3 h at 1550 °C under nitrogen at ambient pressure); grain growth was suppressed by grain-boundary pinning, and high flexural strength over 630 MPa could be obtained. With two-step sintering process, the morphology of second phase was changed from interconnected structure to isolated structure; this two-step process limited grain growth and increased thermal conductivity. The highest thermal conductivity (156 Wm$^{-1}$ K$^{-1}$) was achieved by two-step sintering, and the ceramic showed moderate flexural strength (560 MPa).

Keywords: Aluminum nitride; CaZrO$_3$; Strength; Thermal conductivity; Sintering

1. Introduction

Aluminum nitride (AlN) is a useful ceramic material for many technical applications like substrate, heat sinks, refractive materials in metallurgical industry, packaging materials for high power integrated circuits for electronic devices, due to its combination of high thermal conductivity, low dielectric constant, high electrical resistance, wide band gap ($E_g = 6.2$ eV at room temperature), chemical inertness, and thermal expansion coefficient (which is close to that of silicon).$^{1-6}$ The thermal conductivity of AlN and the factors affected by it have received much attention for several decades.$^{7-10}$ The high power-density required in many applications can cause crack propagation in ceramic substrates owing to high thermal stresses arising at the joints with circuits. Therefore, for AlN ceramics to be widely useful, they must show high thermal conductivity and good mechanical properties. A few studies have focused on the mechanical properties of AlN. Watari and Hwang investigated the thermal conductivity and flexural strength of LiYO$_2$–CaO-doped AlN ceramics,$^{11}$ finding respective values of 170 Wm$^{-1}$ K$^{-1}$ and 440 MPa. They concluded that both properties were influenced by AlN grain size and the number of grain boundaries.

The flexural strength of AlN ceramics can be improved by eliminating pores and by having smaller grains. However, decreasing the grain size reduces the thermal conductivity of the sintered material. Therefore, new fabrication techniques are sought that produce ceramic substrates with high thermal conductivity and good mechanical properties.

The primary objective of this work is the fabrication of AlN ceramics with both high flexural strength and high thermal conductivity. The AlN ceramics were pressureless sintered at 1450–1700 °C for 3 h with CaZrO$_3$ and Y$_2$O$_3$ additives. CaO–Y$_2$O$_3$ is the most popular additive system for the low-temperature sintering of AlN ceramics due to its low eutectic temperature.$^{12,13}$ However, large grains tend to form in the resulting sintered AlN, leading to poor flexural strength. The inhibition of grain growth is therefore desirable, because it would lead to smaller grains and stronger ceramics. Secondary phase inclusions can inhibit grain growth, and are frequently used for this purpose in sintered ceramics. Lange and Hirlinger used ZrO$_2$...
to inhibit grain growth for Al$_2$O$_3$ sintering. The secondary phases were located at the grain boundaries and they hindered grain growth by exerting a dragging force and by pinning the grain boundary.

CaZrO$_3$ is a phase between CaO–ZrO$_2$ that is stable at high temperature. This sintering additive plays a double role during the sintering process. One is to promote the densification by forming a liquid phase when it is in contact with Al$_2$O$_3$ in presence of certain impurities. Mostly, AlN raw powder contains a small amount of oxygen impurity which is Al$_2$O$_3$ existed on the surface of AlN. The other is to suppress grain growth, keeping the grains small via grain-boundary pinning from the secondary phase. The resulting small grains can yield AlN ceramics with high flexural strength. The addition of CaO can also promote the secondary phase to be located at the boundaries of the AlN grains during sintering.

Sintering in two-steps can produce AlN ceramics that are both strong and highly thermal conductive. Chen and Wang introduced this technique to suppress grain growth during the final stage of sintering. The thermal conductivity of AlN ceramics is affected by phonon-defect scattering caused by oxygen-related defects and secondary phases.

This work reports the two-step sintering of AlN ceramics with CaZrO$_3$ and Y$_2$O$_3$ additives. The additives suppressed grain growth, and the two-step sintering process provided high thermal conductivity without reducing flexural strength. The second step of the sintering was conducted at temperatures that allowed active grain boundary diffusion but hindered grain boundary migration. Consequently, densification and purification of the AlN lattice were able to continue without significant grain growth.

### 2. Experimental procedure

#### 2.1. Powders and processing

Green AlN specimens were prepared using commercial high-purity AlN power (particle size 1.0 μm, specific surface area 3.27 m$^2$ g$^{-1}$; E grade, Tokuyama Corp., Tokyo, Japan) with additives of CaZrO$_3$ (particle size <50 nm, Aldrich, USA) and Y$_2$O$_3$ (particle size 30 nm, Aldrich, USA). Three systems employing both additives were tested: both additives were each used at 1 wt. % (system CzY), 2 wt. % (Cz2Y2), and 3 wt. % (Cz3Y3). The AlN powder and the additives were ball milled using zirconia balls for 24 h in a polyethylene bottle with 2-propanol as liquid medium. After mixing, the slurry was dried on a hot plate with stirring. The dried powder was sieved through a 30 μm diameter disk under a pressure of 30 kg cm$^{-2}$, and was cold isostatic pressed (CIP) at 200 MPa. Similarly prepared systems of only Y$_2$O$_3$-doped AlN (system Y) was also tested for comparison.

#### 2.2. Sintering

All the systems were sintered using both one-step and two-step regimes. The green bodies shaped through CIP were sintered between two boron nitride (BN) plates. Sintering was at 1450–1700 °C for 3 h under a nitrogen atmosphere in a graphite furnace (ASTRO, Thermal Technology, Santa Barbara, CA). The heating rate during sintering was 10 °C/min; the cooling rate was 25 °C/min.

Two-step sintering was conducted using different temperatures to minimize grain growth. The second sintering temperature was selected to promote densification and purification of the AlN lattice without allowing grain growth. During the first step, specimens were heated to $T_1$ with rate of 10 °C/min and held for 3 h at $T_1$. They were cooled at 25 °C/min to a lower sintering temperature $T_2$, which was then maintained for 2 h.

### 2.3. Characterization

Bulk density was measured by Archimedes’ method. The microstructure of the centre surfaces and the mean diameter of the grains were characterized by scanning electron microscopy (FE-SEM; Philips XL30 FEG, Eindhoven, Netherlands) and transmission electron microscopy (TEM; Tecnai G$^2$ F30 S-twin FEI, Eindhoven, The Netherlands). The thermal conductivity at room temperature was measured by the laser flash method with a glass–Nd laser and an InSb infrared sensor using a Xenon Flash instrument (LFA 447 Nanoflash, Netzsch Instruments Inc., Burlington, USA). The precision of this apparatus is estimated to be ±3 %. Each reported thermal conductivity is an average of three measurements.

The flexural strength of 1.5 mm × 2.0 mm × 15 mm rectangular bars was tested using a 10 mm support span and a crosshead speed of 0.2 mm/min. Sintered disks were cut into bars for the measurements. The bars were polished with 6 μm diamond paste in alcohol-based slurry (Blue Lube, Struers) and flaws on either side of each bar were removed. The reported flexural strength is an average of the test results of ten bending bars.

### 3. Result and discussion

#### 3.1. Densification behavior

The AlN ceramics sintered with various additive concentrations showed bulk density values that depended on the sintering temperature (Fig. 1). The green densities of the powder compacts were approximately 57–60 % of theoretical density (TD). The density of each specimen increased as the sintering temperature increased from room temperature to 1550 °C. The theoretical density of AlN was reached by each sample, with the exception of sample Y, when sintered at over 1550 °C. Sample Y, which lacked CaZrO$_3$, achieved only 81 % of the TD after sintering at 1550 °C for 3 h (Fig. 1). Overall, the bulk density comparison shows that the use of both CaZrO$_3$ and Y$_2$O$_3$ additives greatly improved the sinterability of AlN ceramics and achieved the lower temperature sintering process. The densification was achieved by means of liquid-phase sintering. The CaZrO$_3$–Y$_2$O$_3$–Al$_2$O$_3$ additive system formed a liquid phase by eutectic melting, which promoted densification at lower temperatures.
Table 1
Flexural strength of AlN sintered at various temperatures.

<table>
<thead>
<tr>
<th>Temperature (°C)</th>
<th>Flexural strength a (MPa)</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>CzY</td>
</tr>
<tr>
<td>1500</td>
<td>579 (60)</td>
</tr>
<tr>
<td>1550</td>
<td>539 (39)</td>
</tr>
<tr>
<td>1600</td>
<td>568 (63)</td>
</tr>
<tr>
<td>1650</td>
<td>517 (19)</td>
</tr>
<tr>
<td>1700</td>
<td>506 (44)</td>
</tr>
</tbody>
</table>

a Standard deviations for ten measurements given in parentheses.

3.2. Flexural strength of AlN

A three-point bending test was conducted on each of the AlN ceramics with two additives after sintering at 1500, 1550, 1600, 1650, and 1700 °C (Table 1 and Fig. 2). Specimens sintered at 1450 °C were not sufficiently dense to warrant strength assessment. Ten samples of each composition were tested at each temperature. Strengths of over 450 MPa were consistently observed at all the tested sintering temperatures. Among the three tested compositions, Cz2Y2 had the highest flexural strength of 630 MPa after sintering at 1550 °C. The flexural strength of this composition initially increased with sintering temperature increased, but it then decreased as the sintering temperature increased above a certain optimal temperature due to the increased promotion of grain growth. The measured strengths of the various compositions showed different trends with respect to sintering temperature. As the amount of additives increased, the sintering temperature required to achieve the highest strength was raised. Sample CzY showed its the highest flexural strength after sintering at 1500 °C, Cz2Y2 was the strongest after sintering at 1550 °C, and Cz3Y3 after sintering at 1650 °C.

The flexural strength of a specimen is generally affected by its pores and grain size. However, all three compositions showed full densification after sintering at over 1500 °C with no pores inside the lattices. The increased addition of CaZrO3 effectively limited grain growth, even during sintering at high temperatures. Fig. 3 shows grain size distributions for the various combinations of sintering temperature and composition. The samples with the smallest grains showed the highest flexural strengths.
Fig. 4. TEM images of (a) CzY, (b) Cz2Y2, (c) Cz3Y3 compositions sintered at 1650 °C.

(Figs. 2 and 3). CzY showed the highest strength and the smallest grains among the three compositions after each was sintered at 1500 °C. Sintering at 1550 °C left Cz2Y2 the strongest ceramic with the smallest grains; Cz3Y3 was the strongest and finest grained of the samples sintered at 1650 °C. Higher additive concentrations maintained small grains in the ceramics sintered at high temperature (1650 °C). Small amount of CaZrO3 additives formed liquid phase by reacting with Al2O3 in advance and the remaining CaZrO3 could inhibit the grain growth by locating at the triple junctions of grains.
The grains of Cz3Y3, the sample with the highest additive concentration, were limited to being 2 μm in size when the sample was sintered at up to 1650 °C. They also showed a narrow distribution of sizes. On the other hand, the grains of CzY and Cz2Y2 showed the grain growth. In both CzY and Cz2Y2 compositions, added small amount of CaZrO3 additives had less effect on inhibiting the grain growth at high temperature, because CaZrO3 reacted with Al2O3 and formed liquid phase. Grain properties tend to affect significantly the strength of the ceramics, with strong materials showing narrow distributions of small grains, as also observed in the ceramics studied here (Figs. 2 and 3).

3.3. Microstructure analysis

Transmission electron microscopy (TEM) analysis of the sintered specimens was conducted to compare the characteristics of their various grains. In Fig. 4(a)–(c) microstructure of AlN sintered at 1600 °C showed similar morphology and grain size. Cz3Y3 showed small, rounded grains in sintered at 1650 °C, while CzY and Cz2Y2 showed large, faceted grains (Fig. 4(d)–(f)). The small grains of Cz3Y3 appeared to exhibit grain-boundary pinning with a secondary phase at the triple junctions among them (Figs. 4 and 5). STEM (scanning transmission electron microscope) and elemental mapping analyses of Cz3Y3 sintered at 1650 °C revealed that the secondary phase was separated into two regions, one brighter than the other (respectively labeled 1 and 2 in Fig. 5(a)). The brighter region at the triple junctions among the grains contained a 1:1 ratio of calcium and zirconium elements, suggesting that the added CaZrO3 was present at these junctions and provided the pinning force at the grain boundaries. Fig. 5(b) also shows zirconium located mainly in the brighter region. The added Y2O3 and a small amount of CaO, which was derived from the added CaZrO3, reacted with Al2O3 from the surface oxide layer of the AlN to form a liquid phase that prevented the diffusion of oxygen into the grains by trapping it at the grain boundaries. The sintering additives affected the grain properties of the ceramics via two separate processes: grain-boundary pinning and the elimination of oxygen-related defects (Fig. 5). These processes allowed grain growth and flexural strength to be controlled by the addition of CaZrO3 and Y2O3. The use of the additives enabled the ceramics to have smaller grains than otherwise observed under similar sintering conditions.

3.4. Enhancement of thermal conductivity by two-step sintering

The use of the additives strengthened the AlN ceramics, and subsequent elaboration of the sintering process (i.e., two-step sintering), further enhanced their thermal conductivity without compromising their strength. Fig. 6 compares the thermal conductivities and flexural strengths of the AlN ceramics sintered at 1600 °C and at two-step temperatures (1600 °C and then 1400 °C). The one-step sintering resulted in thermal conductivities for CzY, Cz2Y2, and Cz3Y3 of 120, 132, and 144 Wm⁻¹ K⁻¹, respectively. The two-step sintered ceramics...
were on average 9.7 % more thermally conductive: their respective thermal conductivities were 132, 147, and 155 Wm$^{-1}$ K$^{-1}$. The flexural strengths and grain sizes of the variously sintered ceramics are compared in Table 2. Two-step sintering led to grains on average 12.6 % larger than those resulting from one-step sintering; though the longer holding time of two-step sintering process showed a minimal grain growth, it did not greatly affect both thermal conductivity and strength. The microstructures of the one- and two-step sintered samples are compared in Fig. 7. Sintering at one temperature resulted in

Table 2

<table>
<thead>
<tr>
<th>Composition</th>
<th>Strength a (MPa)</th>
<th>Grain size (µm)</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>One-step</td>
<td>Two-step</td>
</tr>
<tr>
<td>CzY</td>
<td>568 (60)</td>
<td>592 (39)</td>
</tr>
<tr>
<td>Cz2Y2</td>
<td>562 (82)</td>
<td>501 (55)</td>
</tr>
<tr>
<td>Cz3Y3</td>
<td>568 (48)</td>
<td>560 (42)</td>
</tr>
</tbody>
</table>

a Standard deviations for ten measurements given in parentheses.
a secondary phase along the grain boundaries that formed a continuous channel-like structure (Fig. 7(a)–(c)); in the two-step sintered samples, the secondary phase was isolated at the triple junctions of the grains (Fig. 7(d)–(f)). Such an isolated secondary phase led to reduced phonon-defect scattering, suggesting that the difference in the morphologies of the secondary phase was the main cause of the different thermal conductivities observed here. The isolated secondary phase resulted in enhanced thermal conductivity.

4. Conclusions

This work has demonstrated that the low-temperature (1550°C) sintering of AlN with CaZrO3 and Y2O3 additives resulted in dense ceramics that approached the theoretical density. The CaZrO3–Y2O3 additive system allowed low temperature sintering to produce high-strength AlN materials. The additives limited the grain size to 2 μm in AlN ceramics sintered at up to 1650°C. They also suppressed grain growth during high temperature sintering through grain-boundary pinning. As the amount of additives increased, the sintering temperature required to achieve the highest strength was raised. CaZrO3 and Y2O3 additives, each used at 1 wt.% led to a ceramic with an optimized flexural strength of 579 MPa obtained after sintering at 1500°C. The additives used at 2 wt.% resulted in an optimized strength of 631 MPa with sintering at 1550°C, and flexural strength was maximized at 596 MPa in a system with 3 wt.% of each additive sintered at 1650°C. The thermal conductivities of the AlN ceramics were enhanced by using a two-step sintering process; this did not weaken the ceramics. Phonon-defect scattering related to secondary phases decreased with the introduction of isolated secondary phases during the two-step processing. The highest thermal conductivity shown by the AlN ceramics was 156 Wm⁻¹ K⁻¹, the flexural strength of this two-step-sintered sample was 560 MPa.

Acknowledgments

This study was supported by a grant from the Fundamental R&D Program for Core Technology of Materials funded by the Ministry of Commerce, Industry and Energy, Republic of Korea. This work was also supported by the Basic Science Research Program through the National Research Foundation of Korea (NRF) funded by the Ministry of Education (2009-0094038). The authors wish to express their gratitude to Dr. In-Sig Seog of KCC for his valuable suggestion and support during this study.

References